

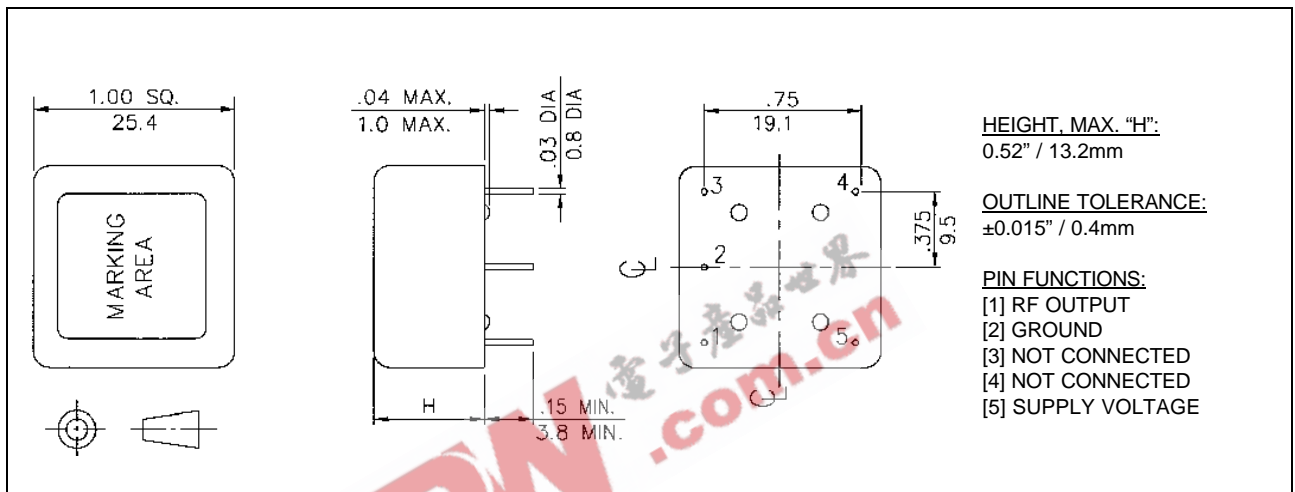
OX4180A-LZ-1-12.800-SM

REFERENCE OSCILLATOR TO SEMTEC ACS8530 STRATUM 3E SYNCHRONIZATION CHIP SET

APPROVALS

RALTRON	CUSTOMER
Created by, date:	Name (please print):
Sales approval, date:	Title (please print):
Eng. approval, date:	Signature, date:
Revision:	

MECHANICAL SPECIFICATION



ELECTRICAL SPECIFICATION

PARAMETER	SYMBOL	CONDITIONS	VALUE	UNIT
Supply voltage, nom.	Vs	Vs±5%	3.3	V
Power dissipation, max.	Ps	Vs, nom. / Ta=+25°C	1.3	W
Heat up power, max.	Ps_heat	Vs, nom. / Ta=+25°C	3.5	W
Heat up time, max.	t_heat (Ta)	Vs, nom. / Ta=+25°C	5.0	min
Frequency nom.	fo	-	12.800	MHz
Frequency calibration	Δf/fo	Ta=+25°C, Pre-Reflow	±1.5	ppm
Freq. stability vs. temperature	Δf/fc (Ta)	Ta=0°C...+70°C	±0.01	ppm
Freq. stability vs. supply voltage	Δf/fc (ΔVcc)	Per %change in voltage, max. : ±5%	±0.002	ppm
Total freq. stability	Δf/fo	over all causes including 20 year aging	±4.0	ppm
Drift	D	for 24 hrs. in a ±3°C temperature range anywhere within the operating temperature range	±0.04	ppm
Short term stability	Δf/fc(Δt)	Δt=1sec. (Allan variance)	10E-11
Phase noise @ freq. offset	£ (Δf)	Δf=100Hz	-130	dBc/Hz
	£ (Δf)	Δf=1kHz	-145	dBc/Hz
	£ (Δf)	Δf=10kHz	-150	dBc/Hz
	£ (Δf)	Δf=100kHz	-150	dBc/Hz
HCMOS/TTL compatible output levels	VOH / VOL	load=10pF; Vs, nom.	2.97/ 0.3	V
Duty cycle	DC	load=10pF / @ 50% level	40...60	%
Rise- / fall time	tr / tf	10%~90% Vout, 90%~10% Vout	10.0	ns
Storage temperature range	Tstg	-	-55...+90	°C

3/12/2001 marketing-rfq. ocxo, OX80